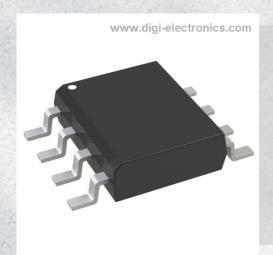


ZXMN6A25DN8TA Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number ZXMN6A25DN8TA-DG

Manufacturer Diodes Incorporated

Manufacturer Product Number ZXMN6A25DN8TA

Description MOSFET 2N-CH 60V 3.8A 8SO

Detailed Description Mosfet Array 60V 3.8A 1.8W Surface Mount 8-SO



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
ZXMN6A25DN8TA	Diodes Incorporated
Series:	Product Status:
	Active
Technology:	Configuration:
MOSFET (Metal Oxide)	2 N-Channel (Dual)
FET Feature:	Drain to Source Voltage (Vdss):
Logic Level Gate	60V
Current - Continuous Drain (Id) @ 25°C:	Rds On (Max) @ Id, Vgs:
3.8A	50m0hm @ 3.6A, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
1V @ 250μA (Min)	20.4nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds:	Power - Max:
1063pF @ 30V	1.8W
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
8-SOIC (0.154", 3.90mm Width)	8-50
Base Product Number:	
ZXMN6	

Environmental & Export classification

8541.29.0095

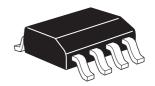
RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



ZXMN6A25DN8 Dual 60V SO8 N-channel enhancement mode MOSFET

Summary

V _{(BR)DSS}	$R_{DS(on)}$ (Ω)	I _D (A)
60	0.050 @ V _{GS} = 10V	5
00	0.070 @ V _{GS} = 4.5V	4.2



Description

This new generation trench MOSFET from Zetex features a unique structure combining the benefits of low on-resistance and fast switching, making it ideal for high efficiency power management applications.

Features

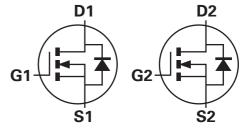
- · Low on-resistance
- · Fast switching speed
- · Low gate drive
- · Low profile SO8 package

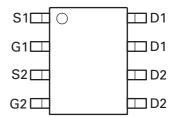
Applications

- · DC DC converters
- · Power management functions
- Motor control

Ordering information

Device	Reel (inches)	Tape width (mm)	Quantity per reel
ZXMN6A25DN8TA	7	12	500
ZXMN6A25DN8TC	13	12	2500





Pin out - top view

Device marking

ZXMN 6A25D

Absolute maximum ratings

Parameter	Symbol	Limit	Unit	
Drain-source voltage	V _{DSS}	60	V	
Gate-source voltage	V _{GS}	±20	V	
Continuous drain current @V _{GS} =10V; T _{amb} =25°C ^{(b) (d)}		5	Α	
@V _{GS} =10V; T _{amb} =70°C ^{(b) (d)}	I _D	4	Α	
@V _{GS} =10V; T _{amb} =25°C ^{(a) (d)}		3.8	Α	
Pulsed drain current ^(c)	I _{DM}	24	Α	
Continuous source current (body diode) ^(b)	I _S	3.4	Α	
Pulsed source current (body diode) ^(c)	I _{SM}	24	Α	
Power dissipation at T _{amb} =25°C ^{(a) (d)}	P _D	1.25	W	
Linear derating factor		10	mW/°C	
Power dissipation at T _{amb} =25°C ^{(a) (e)}	P _D	1.8	W	
Linear derating factor		14	mW/°C	
Power dissipation at T _{amb} =25°C ^{(b) (d)}	P _D	2.1	W	
Linear derating factor		17	mW/°C	
Operating and storage temperature range	T _j :T _{stg}	-55 to +150	°C	

Thermal resistance

Parameter	Symbol	Limit	Unit
Junction to ambient ^{(a) (d)}	$R_{\Theta JA}$	100	°C/W
Junction to ambient ^{(a) (e)}	$R_{\Theta JA}$	70	°C/W
Junction to ambient ^{(b) (d)}	$R_{\Theta JA}$	60	°C/W

NOTES:

⁽a) For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

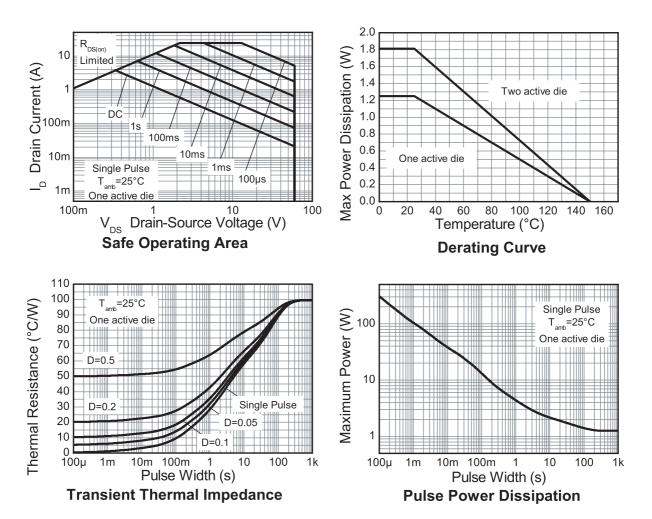
⁽b) For a device surface mounted on FR4 PCB measured at t \leq 10 sec.

⁽c) Repetitive rating 25mm x 25mm FR4 PCB, D=0.02, pulse width= $300\mu s$ - pulse width limited by maximum junction temperature.

⁽d) For a dual device with one active die.

⁽e) For a device with two active die running at equal power.

Typical characteristics



Electrical characteristics (at T_{amb} = 25°C unless otherwise stated)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Static			•	•		
Drain-source breakdown voltage	V _{(BR)DSS}	60			V	I _D =250μA, V _{GS} =0V
Zero gate voltage drain current	I _{DSS}			1.0	mA	V _{DS} =60V, V _{GS} =0V
Gate-body leakage	I _{GSS}			100	nA	V _{GS} =±20V, V _{DS} =0V
Gate-source threshold voltage	V _{GS(th)}	1.0			V	$I_D=250\mu A$, $V_{DS}=V_{GS}$
Static drain-source on-state	R _{DS(on)}			0.050	Ω	V _{GS} =10V, I _D =3.6A
resistance ^(*)				0.070	Ω	V _{GS} =4.5V, I _D =3A
Forward transconductance (*)(‡)	9 _{fs}		10.2		S	V _{DS} =15V,I _D =4.5A
Dynamic ^(‡)	•			•		
Input capacitance	C _{iss}		1063		pF	.,
Output capacitance	C _{oss}		104		pF	V _{DS} =30V, V _{GS} =0V,f=1MHz
Reverse transfer capacitance	C _{rss}		64		pF	VGS-0 V/I- 1111112
Switching (†) (‡)	•			l		
Turn-on delay time	t _{d(on)}		3.8		ns	
Rise time	t _r		4.0		ns	V _{DD} =30V, I _D =1A
Turn-off delay time	t _{d(off)}		26.2		ns	RG≅6.0Ω, V _{GS} =10V
Fall Time	t _f		10.6		ns	
Gate charge	Qg		11.0		nC	V_{DS} =30V, V_{GS} =5V, I_{D} =4.5A
Total gate charge	Qg		20.4		nC	V _{DS} =30V,V _{GS} =10V,
Gate-source charge	O _{gs}		4.1		nC	I _D =4.5A
Gate-drain charge	Q_{gd}		5.1		nC	
Source-drain diode	1					
Diode Forward Voltage ^(*)	V _{SD}		0.85	0.95	V	T _J =25°C, I _S =5.5A,V _{GS} =0V
Reverse recovery time ^(‡)	t _{rr}		22.0		ns	T _J =25°C, I _F =2.2A,
Reverse recovery charge ^(‡)	Q _{rr}		21.4		nC	di/dt= 100A/μs

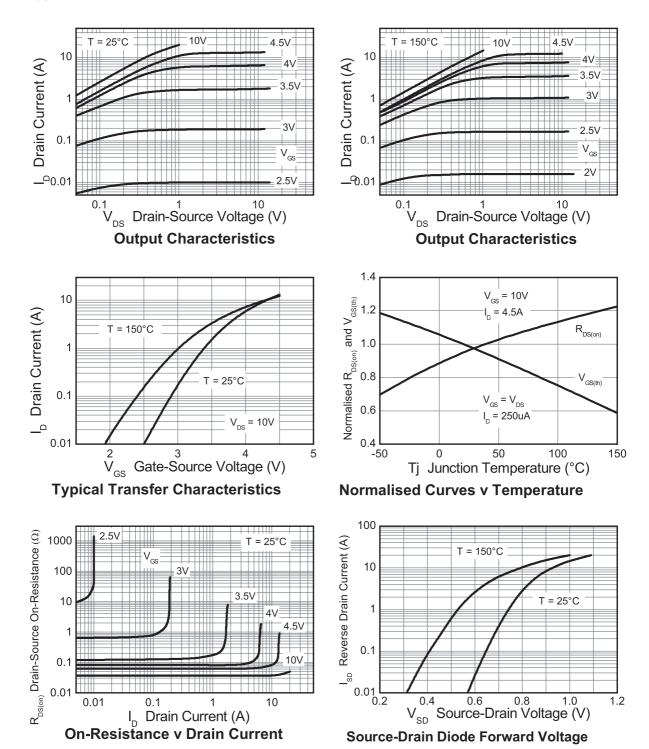
NOTES:

^(*) Measured under pulsed conditions. Width=300 $\mu s.$ Duty cycle $\leq 2\%$.

^(†) Switching characteristics are independent of operating junction temperature.

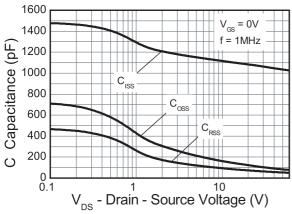
^(‡) For design aid only, not subject to production testing.

Typical characteristics



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Typical characteristics



V_{GS} Gate-Source Voltage (V) $V_{DS} = 30V$ 10 20

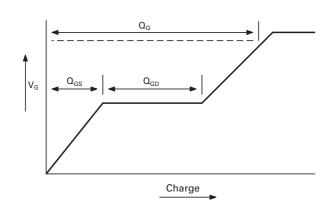
= 4.5A

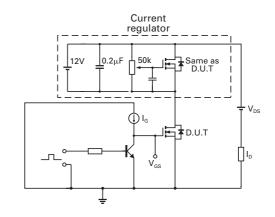
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Capacitance v Drain-Source Voltage

Gate-Source Voltage v Gate Charge

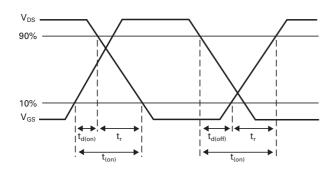
Q - Charge (nC)

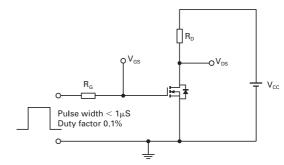




Basic gate charge waveform

Gate charge test circuit

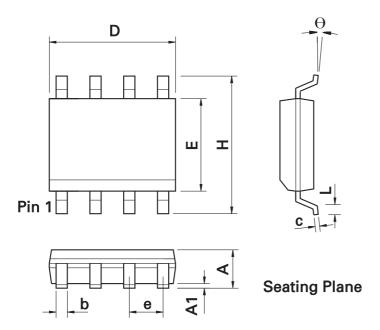




Switching time waveforms

Switching time test circuit

Package outline - SO8



DIM	Inc	hes	Millin	neters	DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
Α	0.053	0.069	1.35	1.75	е	0.050	BSC	1.27	BSC
A1	0.004	0.010	0.10	0.25	b	0.013	0.020	0.33	0.51
D	0.189	0.197	4.80	5.00	С	0.008	0.010	0.19	0.25
Н	0.228	0.244	5.80	6.20	θ	0°	8°	0°	8°
Е	0.150	0.157	3.80	4.00	h	0.010	0.020	0.25	0.50
L	0.016	0.050	0.40	1.27	-	-	-	-	-

Note: Controlling dimensions are in inches. Approximate dimensions are provided in millimeters

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